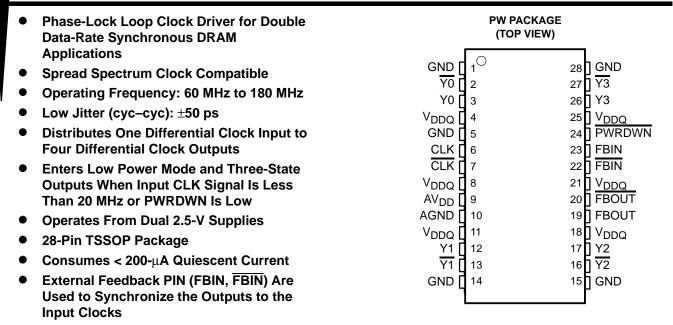
CDCV855, CDCV855I 2.5-V PHASE-LOCK LOOP CLOCK DRIVER

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description

The CDCV855 is a high-performance, low-skew, low-jitter zero delay buffer that distributes a differential clock input pair (CLK, $\overline{\text{CLK}}$) to four differential pairs of clock outputs (Y[0:3], $\overline{\text{Y[0:3]}}$) and one differential pair of feedback clock outputs (FBOUT, $\overline{\text{FBOUT}}$). When $\overline{\text{PWRDWN}}$ is high, the outputs switch in phase and frequency with CLK. When $\overline{\text{PWRDWN}}$ is low, all outputs are disabled to a high-impedance state (3-state), and the PLL is shut down (low-power mode). The device also enters this low-power mode when the input frequency falls below a suggested detection frequency that is below 20 MHz (typical 10 MHz). An input frequency detection circuit detects the low-frequency condition and after applying a >20-MHz input signal this detection circuit turns on the PLL again and enables the outputs.

When AV_{DD} is tied to GND, the PLL is turned off and bypassed for test purposes. The CDCV855 is also able to track spread spectrum clocking for reduced EMI.

Since the CDCV855 is based on PLL circuitry, it requires a stabilization time to achieve phase-lock of the PLL. This stabilization time is required following power up. The CDCV855 is characterized for both commercial and industrial temperature ranges.

AVAILABLE OPTIONS

| T . | PACKAGED DEVICES |
|---------------|------------------|
| ТА | TSSOP (PW) |
| 0°C to 70°C | CDCV855PW |
| -40°C to 85°C | CDCV855IPW |



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



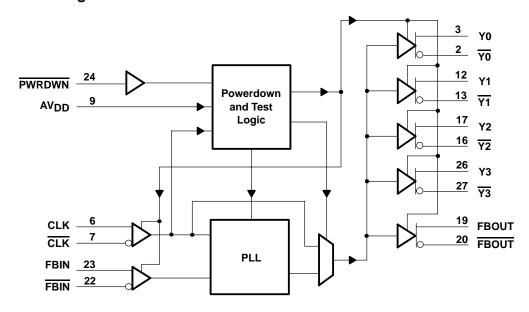
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FUNCTION TABLE (Select Functions)

| | INPUT | 'S | | | | PLL | | |
|------------------|--------|----------------------|----------------------|--------|--------|-------|-------|--------------|
| AV _{DD} | PWRDWN | CLK | CLK | Y[0:3] | Y[0:3] | FBOUT | FBOUT | |
| GND | Н | L | Н | L | Н | L | Н | Bypassed/Off |
| GND | Н | Н | L | Н | L | Н | L | Bypassed/Off |
| X | L | L | Н | Z | Z | Z | Z | Off |
| X | L | Н | L | Z | Z | Z | Z | Off |
| 2.5 V (nom) | Н | L | Н | L | Н | L | Н | On |
| 2.5 V (nom) | Н | Н | L | Н | L | Н | L | On |
| 2.5 V (nom) | X | <20 MHz [†] | <20 MHz [†] | Z | Z | Z | Z | Off |

[†] Typically 10 MHz

functional block diagram



Terminal Functions

| TER | MINAL | | DECORIDATION |
|--------------|----------------------|-----|---|
| NAME | NO. | 1/0 | DESCRIPTION |
| AGND | 10 | | Ground for 2.5-V analog supply |
| AV_{DD} | 9 | | 2.5-V analog supply |
| CLK, CLK | 6, 7 | 1 | Differential clock input |
| FBIN, FBIN | 23, 22 | 1 | Feedback differential clock input |
| FBOUT, FBOUT | 19, 20 | 0 | Feedback differential clock output |
| GND | 1, 5, 14, 15, 28 | | Ground |
| PWRDWN | 24 | 1 | Control input to turn device in the power-down mode |
| V_{DDQ} | 4, 8, 11, 18, 21, 25 | | 2.5-V supply |
| Y[0:3] | 3, 12, 17, 26 | 0 | Buffered output copies of input clock, CLK |
| Y[0:3] | 2, 13, 16, 27 | 0 | Buffered output copies of input clock, CLK |



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absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

| Supply voltage range, V _{DDQ} , AV _{DD} | |
|---|-----------------------------------|
| Input voltage range, V _I (see Notes 1 and 2) | 0.5 V to V _{DDQ} + 0.5 V |
| Output voltage range, VO (see Notes 1 and 2) | 0.5 V to V _{DDQ} + 0.5 V |
| Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{DDQ}$) | ±50 mA |
| Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{DDQ}$) | ±50 mA |
| Continuous output current, $I_O(V_O = 0 \text{ to } V_{DDQ})$ | ±50 mA |
| Continuous current to GND or V _{DDQ} | ±100 mA |
| Package thermal impedance, θ _{JA} (see Note 3): PW package | 105.8°C/W |
| Storage temperature range T _{stq} | –65°C to 150°C |

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

- 2. This value is limited to 3.6 V maximum.
- 3. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 4)

| | | MIN | TYP | MAX | UNIT |
|---|----------------------|----------------------------|---------------------|----------------------------|------|
| Supply voltage, V _{DDQ} , AV _{DD} | | 2.3 | | 2.7 | V |
| Law law Band on tank | CLK, CLK, FBIN, FBIN | | | V _{DDQ} /2 – 0.18 | |
| Low-level input voltage, V _{IL} | PWRDWN | -0.3 | | 0.7 | V |
| I Pale Javed Secretaria Name A | CLK, CLK, FBIN, FBIN | V _{DDQ} /2 + 0.18 | | | |
| High-level input voltage, V _{IH} | PWRDWN | 1.7 | | V _{DDQ} + 0.3 | V |
| DC input signal voltage (see Note 5) | | -0.3 | | V_{DDQ} | V |
| Differential input signal voltage, V _{ID} (see Note 6) | CLK, FBIN | 0.36 | | V _{DDQ} + 0.6 | V |
| Output differential cross-voltage, $V_{O(X)}$ (see Note 7) | | V _{DDQ} /2 - 0.2 | V _{DDQ} /2 | V _{DDQ} /2 + 0.2 | V |
| Input differential pair cross-voltage, $V_{I(X)}$ (see Note 7 | 7) | V _{DDQ} /2 - 0.2 | | $V_{DDQ}/2 + 0.2$ | V |
| High-level output current, IOH | | | | -12 | mA |
| Low-level output current, IOL | | | | 12 | mA |
| Input slew rate, SR (see Figure 7) | | 1 | | 4 | V/ns |
| On senting from air to sent one T | Commercial | 0 | | 85 | 00 |
| Operating free-air temperature, T _A | Industrial | -40 | | 85 | °C |

NOTES: 4. Unused inputs must be held high or low to prevent them from floating.

- 5. DC input signal voltage specifies the allowable dc execution of differential input.
- 6. Differential input signal voltage specifies the differential voltage |VTR VCP| required for switching, where VTR is the true input level and VCP is the complementary input level.
- 7. Differential cross-point voltage is expected to track variations of V_{DDQ} and is the voltage at which the differential signals must be crossing.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| | PARAMETER | | TEST C | ONDITIONS | MIN | TYP† | MAX | UNIT |
|---------------------|--|--------------------|---|-------------------------------|---------------------------|---------------------|---------------------------|------|
| VIK | Input voltage | All inputs | $V_{DDQ} = 2.3 V,$ | I _I = -18 mA | | | -1.2 | V |
| V | High lavel autout | | V _{DDQ} = min to max | c, I _{OH} = -1 mA | V _{DDQ} – 0.1 | | | V |
| VOH | High-level output | voitage | $V_{DDQ} = 2.3 V$, | $I_{OH} = -12 \text{ mA}$ | 1.7 | | | V |
| V | Low lovel output | voltogo | V _{DDQ} = min to max | k , $I_{OL} = 1 \text{ mA}$ | | | 0.1 | V |
| VOL | Low-level output voltage | | $V_{DDQ} = 2.3 V,$ | $I_{OL} = 12 \text{ mA}$ | | | 0.6 | V |
| ЮН | High-level output | current | $V_{DDQ} = 2.3 V,$ | V _O = 1 V | -18 | -32 | | mA |
| loL | Low-level output | current | $V_{DDQ} = 2.3 V,$ | V _O = 1.2 V | 26 | 35 | | mA |
| V_{OD} | Output voltage sv | wing | Differential outputs | are terminated with | 1.1 | | V _{DDQ} – 0.4 | |
| VOX | Output differential cross-voltage [‡] | | Differential outputs are terminated with 120 Ω | | V _{DDQ} /2 – 0.2 | V _{DDQ} /2 | V _{DDQ} /2 + 0.2 | V |
| lį | Input current | | $V_{DDQ} = 2.7 V$, | V _I = 0 V to 2.7 V | | | ±10 | μΑ |
| I _{OZ} | High-impedance- current | state output | V _{DDQ} = 2.7 V, | $V_O = V_{DDQ}$ or GND | | | ±10 | μΑ |
| I _{DD(PD)} | Power-down curr V _{DDQ} + AV _{DD} | ent on | CLK and $\overline{\text{CLK}} = 0 \text{ N}$ Σ of IDD and AIDD | IHz; PWRDWN = Low; | | 100 | 200 | μΑ |
| | | ., | Differential outputs are terminated with 120 Ω / CL = 14 pF | , ,,,,,,,,, | | 150 | 180 | |
| IDD | Dynamic current | on VDDQ | Differential outputs are terminated with $120 \Omega / CL = 0 pF$ | f _O = 167 MHz | | 130 | 160 | mA |
| AI_{DD} | Supply current or | n AV _{DD} | f _O = 167 MHz | | | 8 | 10 | mA |
| Cl | Input capacitance | 9 | V _{DDQ} = 2.5 V | $V_I = V_{DDQ}$ or GND | 2 | 2.5 | 3 | pF |
| CO | Output capacitan | се | V _{DDQ} = 2.5 V | $V_O = V_{DDQ}$ or GND | 2.5 | 3 | 3.5 | pF |

[†] All typical values are at respective nominal VDDQ.

timing requirements over recommended ranges of supply voltage and operating free-air temperature

| | PARAMETER | MIN | MAX | UNIT |
|------|-----------------------------------|-----|-----|------|
| fCLK | Operating clock frequency | 60 | 180 | MHz |
| | Input clock duty cycle | 40% | 60% | |
| | Stabilization time (PLL mode) | | 10 | μs |
| | Stabilization time (Bypass mode)§ | | 30 | ns |

[§] Recovery time required when the device goes from power-down mode into bypass mode (test mode with AVDD at GND).



Differential cross-point voltage is expected to track variation of VDDQ and is the voltage at which the differential signals must be crossing.

Time required for the integrated PLL circuit to obtain phase lock of its feedback signal to its reference signal. For phase lock to be obtained, a fixed-frequency, fixed-phase reference signal must be present at CLK. Until phase lock is obtained, the specifications for propagation delay, skew, and jitter parameters given in the switching characteristics table are not applicable. This parameter does not apply for input modulation under SSC application.

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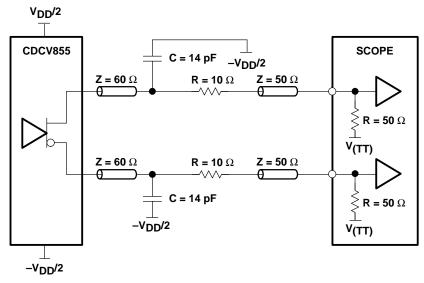
switching characteristics

| | PARAMETER | TES | T CONDITIONS | MIN | TYP [†] MAX | UNIT |
|-------------------------------------|--|---------------------|---------------------|-------------|----------------------|------|
| ^t PLH [‡] | Low-to-high level propagation delay time | Test mod | e/CLK to any output | | 4.5 | ns |
| ^t PHL [‡] | High-to-low level propagation delay time | Test mod | e/CLK to any output | | 4.5 | ns |
| . 8 | | 66 MHz | | – 55 | 55 | ps |
| ^t jit(per) [§] | Jitter (period), See Figure 5 | 100/133/167/180 MHz | | -35 | 35 | ps |
| | | 66 MHz | | -60 | 60 | |
| tjit(cc)§ | Jitter (cycle-to-cycle), See Figure 2 | 100/133/ | 167/180 MHz | -50 | 50 | ps |
| | | 66 MHz | | -130 | 130 | |
| ^t jit(hper) [§] | Half-period jitter, See Figure 6 | 100 MHz | | -90 | 90 | ps |
| , (1) | | 133/167/ | 180 MHz | -75 | 75 | |
| | 0 | Load = 120Ω / 14 pF | | | 2 | V/ns |
| ^t slr(o) | Output clock slew rate, See Figure 7 | Load = 12 | 20Ω / 4 pF | 1 | 3 | V/ns |
| | | SSC off | 66 MHz | -180 1 | | |
| | | | 100/133 MHz | -130 | 130 | 0 ps |
| . 8 | Dynamic phase offset (this includes jitter), | | 167/180 MHz | -90 | 90 | |
| ^t d(Ø) [§] | See Figure 3(b) | | 66 MHz | -230 | 230 | |
| | | SSC on | 100/133 MHz | -170 | 170 | |
| | | | 167/180 MHz | -100 | 100 | |
| | 0 | 66 MHz | | -150 | 150 | |
| ^t (Ø) | Static phase offset, See Figure 3(a) | 100/133/167/180 MHz | | | 100 | ps |
| tsk _(O) ¶ | Output skew, See Figure 4 | | | | 50 | ps |
| tr, tf | Output rise and fall times (20% – 80%) | Load: 120 |) Ω/14 pF | 650 | 900 | ps |

[†] All typical values are at a respective nominal V_{DDQ}. ‡ Refers to transition of noninverting output

[§] This parameter is assured by design but can not be 100% production tested. ¶ All differential output pins are terminated with 120 Ω /14 pF.

PARAMETER MEASUREMENT INFORMATION



NOTE: $V_{(TT)} = GND$

Figure 1. Output Load Test Circuit

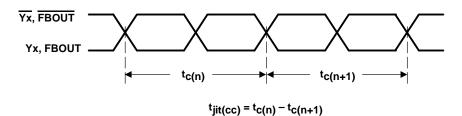
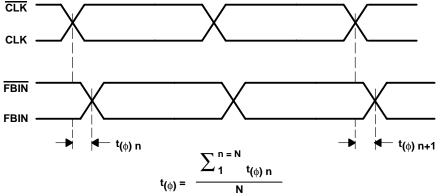


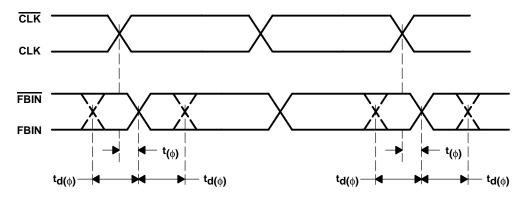
Figure 2. Cycle-to-Cycle Jitter

PARAMETER MEASUREMENT INFORMATION



(N is a Large Number of Samples)

(a) Static Phase Offset



(b) Dynamic Phase Offset

Figure 3. Phase Offset

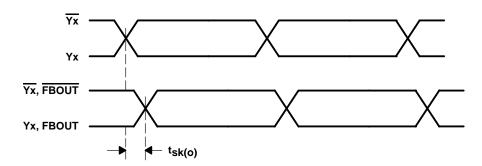


Figure 4. Output Skew

PARAMETER MEASUREMENT INFORMATION

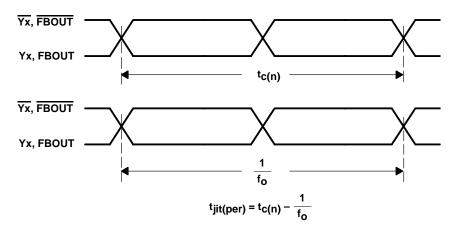


Figure 5. Period Jitter

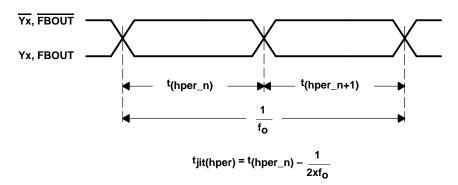


Figure 6. Half-Period Jitter

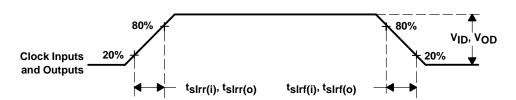


Figure 7. Input and Output Slew Rates

PACKAGE OPTION ADDENDUM



11-Apr-2013

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package Drawing | Pins | Package Qty | Eco Plan | Lead/Ball Finish | MSL Peak Temp | Op Temp (°C) | Top-Side Markings | Samples |
|------------------|--------|--------------|--------------------|------|----------------|----------------------------|------------------|--------------------|--------------|-------------------|---------|
| CDCV855IPW | NRND | TSSOP | PW | 28 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | CDCV855-I | |
| CDCV855IPWG4 | NRND | TSSOP | PW | 28 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | CDCV855-I | |
| CDCV855IPWR | NRND | TSSOP | PW | 28 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | CDCV855-I | |
| CDCV855IPWRG4 | NRND | TSSOP | PW | 28 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | CDCV855-I | |
| CDCV855PW | NRND | TSSOP | PW | 28 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | CDCV855 | |
| CDCV855PWG4 | NRND | TSSOP | PW | 28 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | CDCV855 | |
| CDCV855PWR | NRND | TSSOP | PW | 28 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | CDCV855 | |
| CDCV855PWRG4 | NRND | TSSOP | PW | 28 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | CDCV855 | |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

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Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

PACKAGE OPTION ADDENDUM



11-Apr-2013

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





| | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| CDCV855IPWR | TSSOP | PW | 28 | 2000 | 330.0 | 16.4 | 6.9 | 10.2 | 1.8 | 12.0 | 16.0 | Q1 |
| CDCV855PWR | TSSOP | PW | 28 | 2000 | 330.0 | 16.4 | 6.9 | 10.2 | 1.8 | 12.0 | 16.0 | Q1 |



PACKAGE MATERIALS INFORMATION

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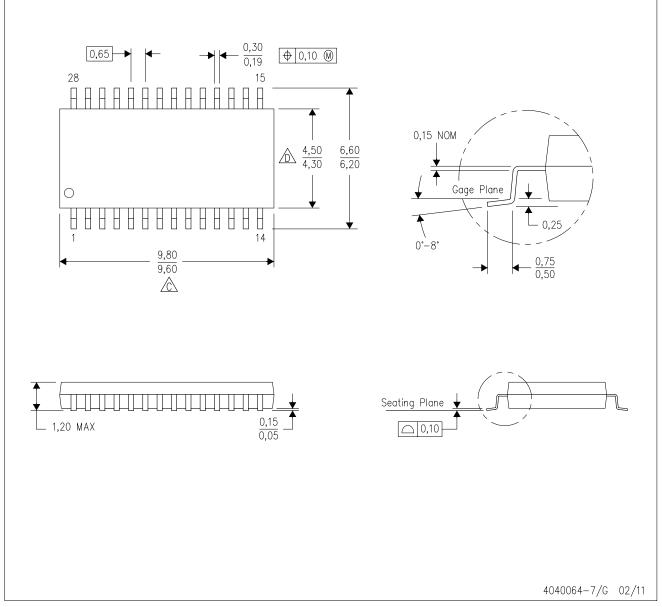


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| CDCV855IPWR | TSSOP | PW | 28 | 2000 | 367.0 | 367.0 | 38.0 |
| CDCV855PWR | TSSOP | PW | 28 | 2000 | 367.0 | 367.0 | 38.0 |

PW (R-PDSO-G28)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G28)

PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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